

### N-Channel NexFET™ Power MOSFETs

Check for Samples: [CSD16301Q2](#)

#### FEATURES

- Ultralow  $Q_g$  and  $Q_{gd}$
- Low Thermal Resistance
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 2-mm x 2-mm Plastic Package

#### APPLICATIONS

- DC-DC Converters
- Battery and Load Management Applications

#### DESCRIPTION

The NexFET™ power MOSFET has been designed to minimize losses in power conversion and load management applications. The SON 2x2 offers excellent thermal performance for the size of the package.

#### PRODUCT SUMMARY

$V_{DS}$	Drain to Source Voltage	25	V
$Q_g$	Gate Charge Total (-4.5V)	2	nC
$Q_{gd}$	Gate Charge Gate to Drain	0.4	nC
$R_{DS(on)}$	Drain to Source On Resistance	$V_{GS} = 3V$	27 mΩ
		$V_{GS} = 4.5V$	23 mΩ
		$V_{GS} = 8V$	19 mΩ
$V_{GS(th)}$	Threshold Voltage	1.1	V

#### ORDERING INFORMATION

Device	Package	Media	Qty	Ship
CSD16301Q2	SON 2-mm x 2-mm Plastic Package	13-Inch Reel	3000	Tape and Reel

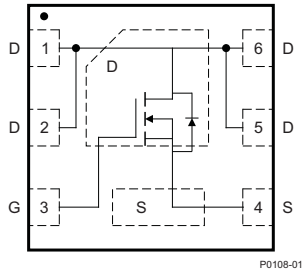
#### ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$ unless otherwise stated		VALUE	UNIT
$V_{DS}$	Drain to Source Voltage	25	V
$V_{GS}$	Gate to Source Voltage	+10 / -8	V
$I_D$	Continuous Drain Current, $T_C = 25^\circ\text{C}$	5	A
	Continuous Drain Current <sup>(1)</sup>	5	A
$I_{DM}$	Pulsed Drain Current, $T_A = 25^\circ\text{C}$ <sup>(2)</sup>	20	A
$P_D$	Power Dissipation <sup>(1)</sup>	2.3	W
$T_J, T_{STG}$	Operating Junction and Storage Temperature Range	-55 to 150	°C
$E_{AS}$	Avalanche Energy, single pulse $I_D = 14A, L = 0.1mH, R_G = 25\Omega$	10	mJ

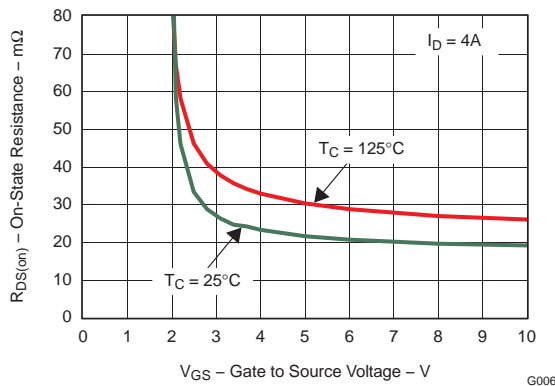
(1) Packaged Limited

(2) Pulse duration 10μs, duty cycle ≤2%

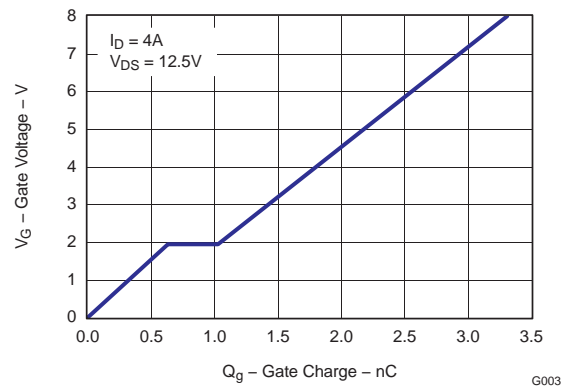
Top View



$R_{DS(on)}$  vs  $V_{GS}$



GATE CHARGE



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NexFET is a trademark of Texas Instruments.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## ELECTRICAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$ , unless otherwise specified

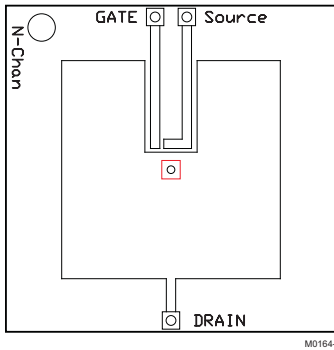
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>Static Characteristics</b>						
$BV_{DSS}$	Drain to Source Voltage	$V_{GS} = 0V, I_D = 250\mu\text{A}$	25			V
$I_{DSS}$	Drain to Source Leakage Current	$V_{GS} = 0V, V_{DS} = 20V$			1	$\mu\text{A}$
$I_{GSS}$	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = +10/-8V$			100	nA
$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_{DS} = 250\mu\text{A}$	0.9	1.1	1.55	V
$R_{DS(on)}$	Drain to Source On Resistance	$V_{GS} = 3V, I_{DS} = 4A$		27	34	m $\Omega$
		$V_{GS} = 4.5V, I_{DS} = 4A$		23	29	m $\Omega$
		$V_{GS} = 8V, I_{DS} = 4A$		19	24	m $\Omega$
$g_{fs}$	Transconductance	$V_{DS} = 15V, I_{DS} = 4A$		16.5		S
<b>Dynamic Characteristics</b>						
$C_{ISS}$	Input Capacitance	$V_{GS} = 0V, V_{DS} = 12.5V, f = 1\text{MHz}$		260	340	pF
$C_{OSS}$	Output Capacitance			165	215	pF
$C_{RSS}$	Reverse Transfer Capacitance			13	17	pF
$R_g$	Series Gate Resistance			1.3	2.6	$\Omega$
$Q_g$	Gate Charge Total (4.5V)	$V_{DS} = 10V, I_{DS} = 4A$		2	2.8	nC
$Q_{gd}$	Gate Charge – Gate to Drain			0.4		nC
$Q_{gs}$	Gate Charge Gate to Source			0.6		nC
$Qg(th)$	Gate Charge at $V_{th}$			0.3		nC
$Q_{OSS}$	Output Charge	$V_{DS} = 12.5V, V_{GS} = 0V$		3		nC
$t_{d(on)}$	Turn On Delay Time	$V_{DS} = 12.5V, V_{GS} = 4.5V, I_{DS} = 4A$ $R_G = 2\Omega$		2.7		ns
$t_r$	Rise Time			4.4		ns
$t_{d(off)}$	Turn Off Delay Time			4.1		ns
$t_f$	Fall Time			1.7		ns
<b>Diode Characteristics</b>						
$V_{SD}$	Diode Forward Voltage	$I_{DS} = 4A, V_{GS} = 0V$		0.8	1	V
$Q_{rr}$	Reverse Recovery Charge	$V_{DD} = 12.5V, I_F = 4A, di/dt = 200A/\mu\text{s}$		5.1		nC
$t_{rr}$	Reverse Recovery Time	$V_{DD} = 12.5V, I_F = 4A, di/dt = 200A/\mu\text{s}$		11		ns

## THERMAL CHARACTERISTICS

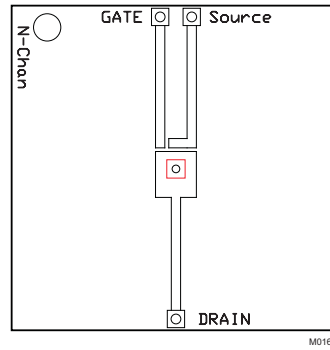
$T_A = 25^\circ\text{C}$ , unless otherwise specified

PARAMETER		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Thermal Resistance Junction to Case <sup>(1)</sup>			8.4	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance Junction to Ambient <sup>(1) (2)</sup>			69	$^\circ\text{C/W}$

- (1)  $R_{\theta JC}$  is determined with the device mounted on a 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch x 1.5-inch (3.81-cm x 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB.  $R_{\theta JC}$  is specified by design, whereas  $R_{\theta JA}$  is determined by the user's board design.
- (2) Device mounted on FR4 material with 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu.



Max  $R_{\theta JA} = 69^{\circ}\text{C/W}$   
when mounted on  
1 inch<sup>2</sup> (6.45 cm<sup>2</sup>) of  
2-oz. (0.071-mm thick)  
Cu.



Max  $R_{\theta JA} = 220^{\circ}\text{C/W}$   
when mounted on  
minimum pad area of  
2-oz. (0.071-mm thick)  
Cu.

### TYPICAL MOSFET CHARACTERISTICS

$T_A = 25^{\circ}\text{C}$ , unless otherwise specified

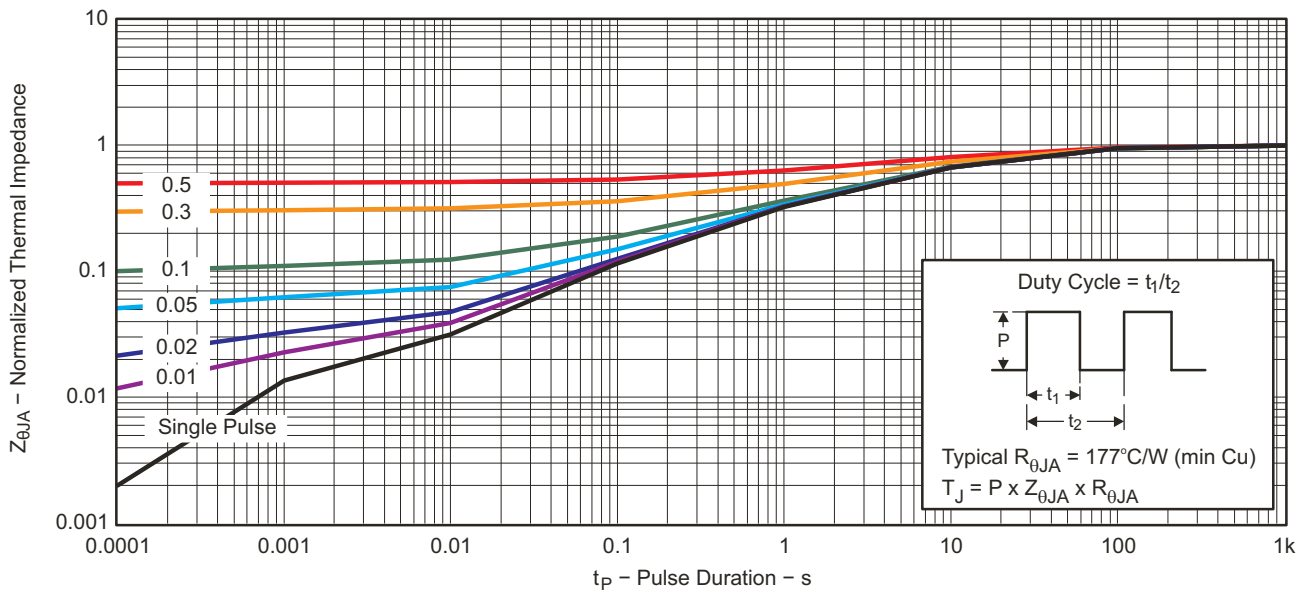
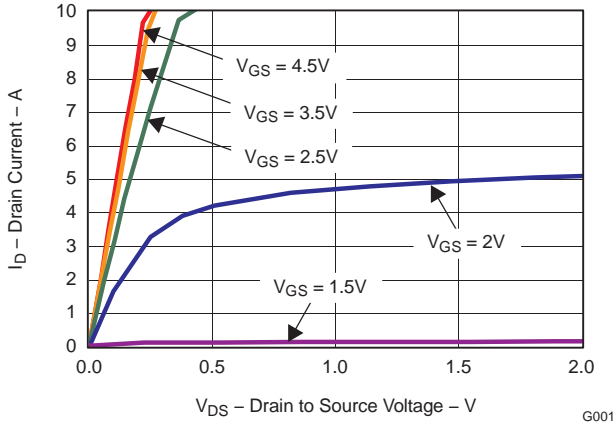


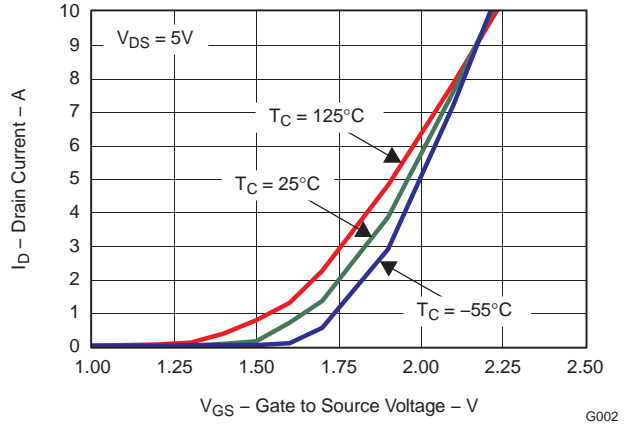
Figure 1. Transient Thermal Impedance

**TYPICAL MOSFET CHARACTERISTICS (continued)**

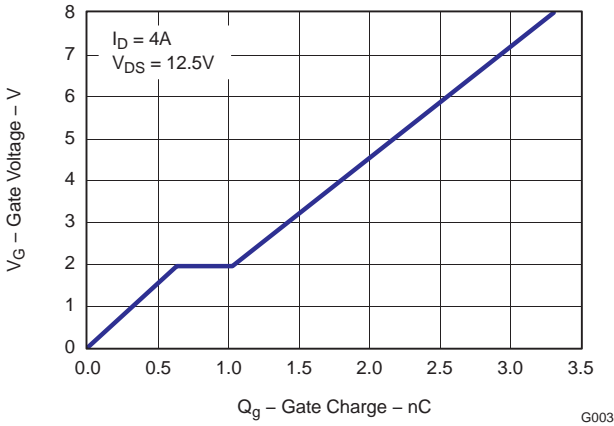
$T_A = 25^\circ\text{C}$ , unless otherwise specified



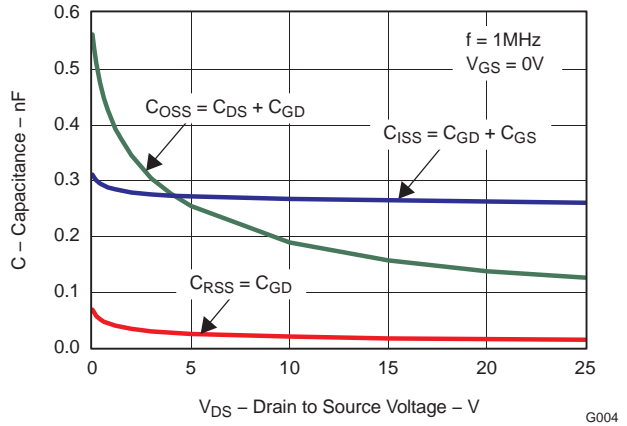
**Figure 2. Saturation Characteristics**



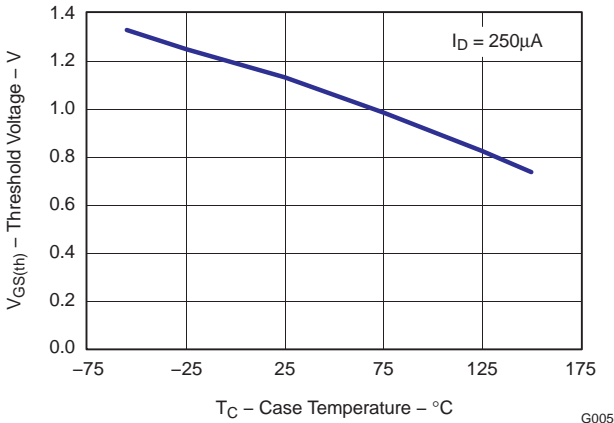
**Figure 3. Transfer Characteristics**



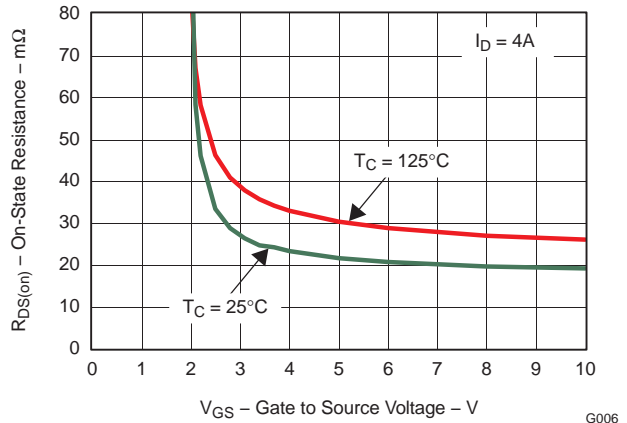
**Figure 4. Gate Charge**



**Figure 5. Capacitance**



**Figure 6. Threshold Voltage vs. Temperature**



**Figure 7. On-State Resistance vs. Gate to Source Voltage**

TYPICAL MOSFET CHARACTERISTICS (continued)

T<sub>A</sub> = 25°C, unless otherwise specified

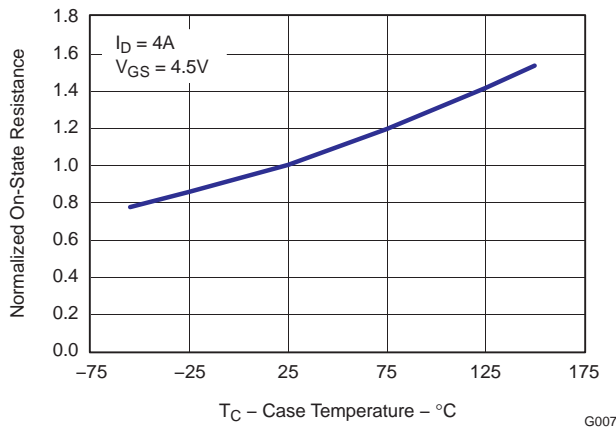


Figure 8. Normalized On-State Resistance vs. Temperature

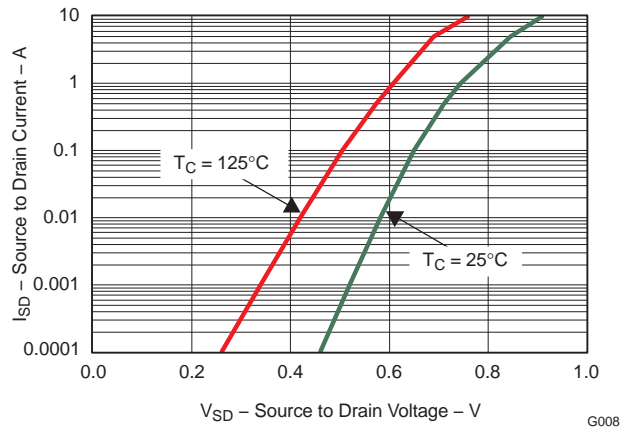


Figure 9. Typical Diode Forward Voltage

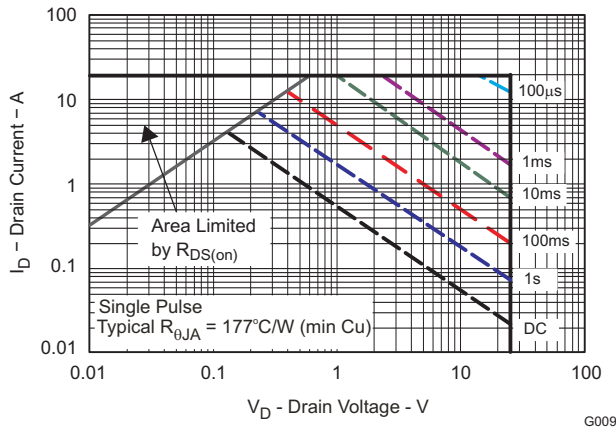


Figure 10. Maximum Safe Operating Area

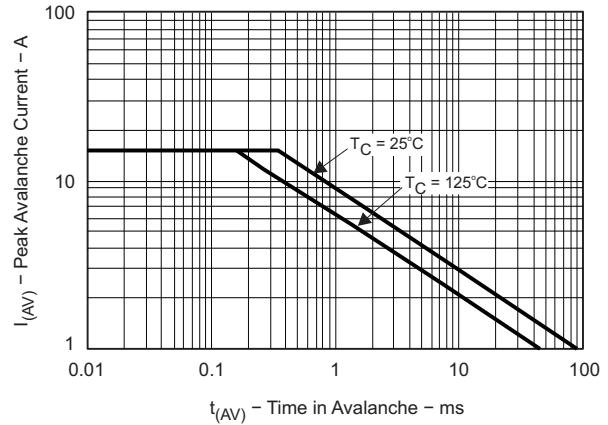


Figure 11. Single Pulse Unclamped Inductive Switching

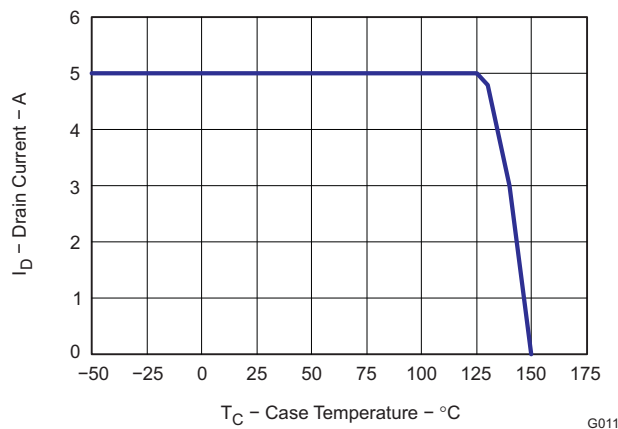
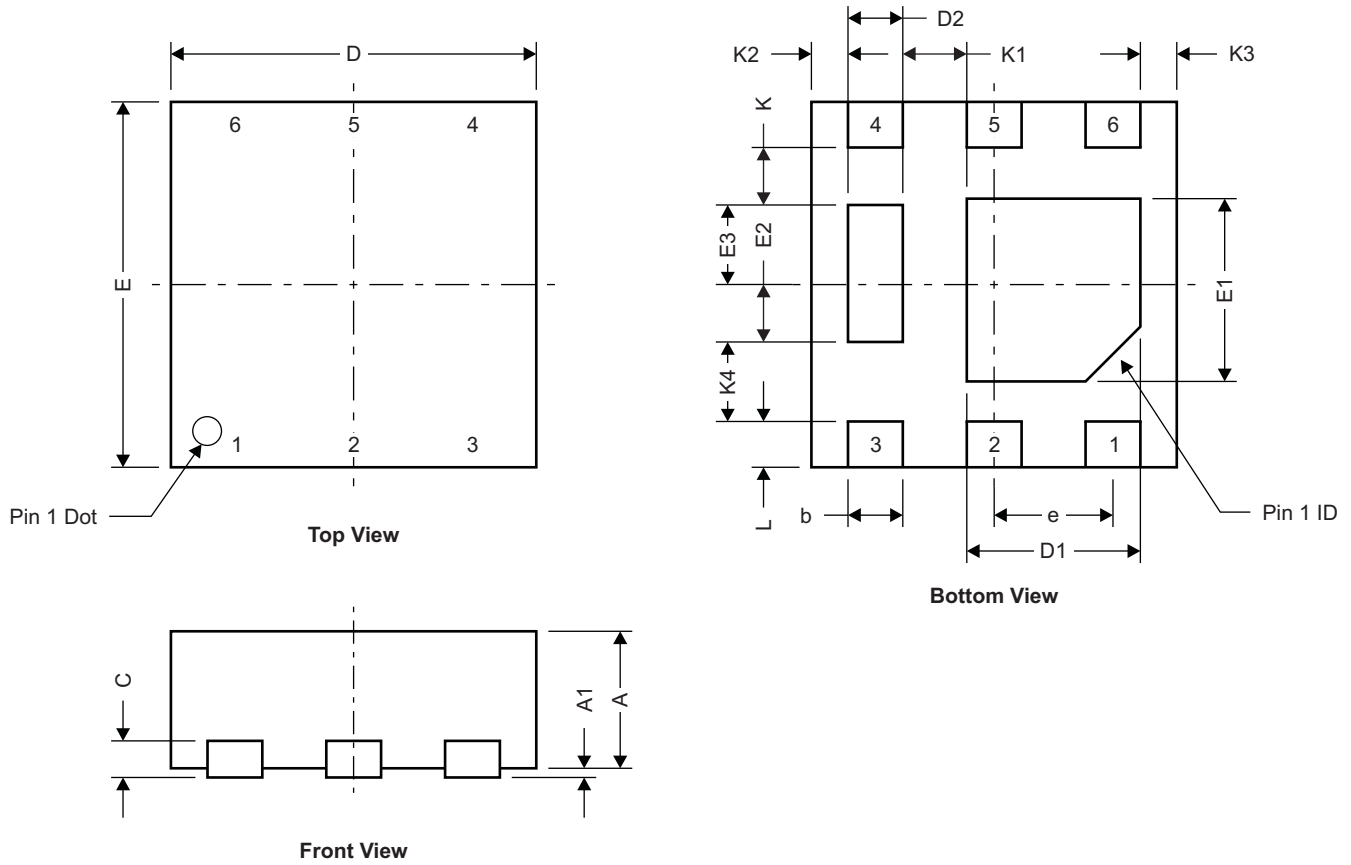


Figure 12. Maximum Drain Current vs. Temperature

**MECHANICAL DATA**

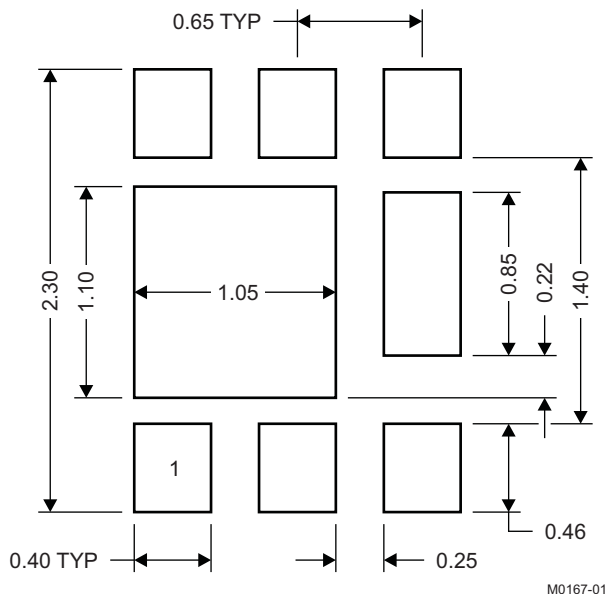
**Q2 Package Dimensions**



M0165-01

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.700	0.750	0.800	0.028	0.030	0.032
A1	0.000		0.050	0.000		0.002
b	0.250	0.300	0.350	0.010	0.012	0.014
C	0.203 TYP			0.008 TYP		
D	2.000 TYP			0.080 TYP		
D1	0.900	0.950	1.000	0.036	0.038	0.040
D2	0.300 TYP			0.012 TYP		
E	2.000 TYP			0.080 TYP		
E1	0.900	1.000	1.100	0.036	0.040	0.044
E2	0.280 TYP			0.0112 TYP		
E3	0.470 TYP			0.0188 TYP		
e	0.650 BSC			0.026 TYP		
K	0.280 TYP			0.0112 TYP		
K1	0.350 TYP			0.014 TYP		
K2	0.200 TYP			0.008 TYP		
K3	0.200 TYP			0.008 TYP		
K4	0.470 TYP			0.0188 TYP		
L	0.200	0.25	0.300	0.008	0.010	0.012

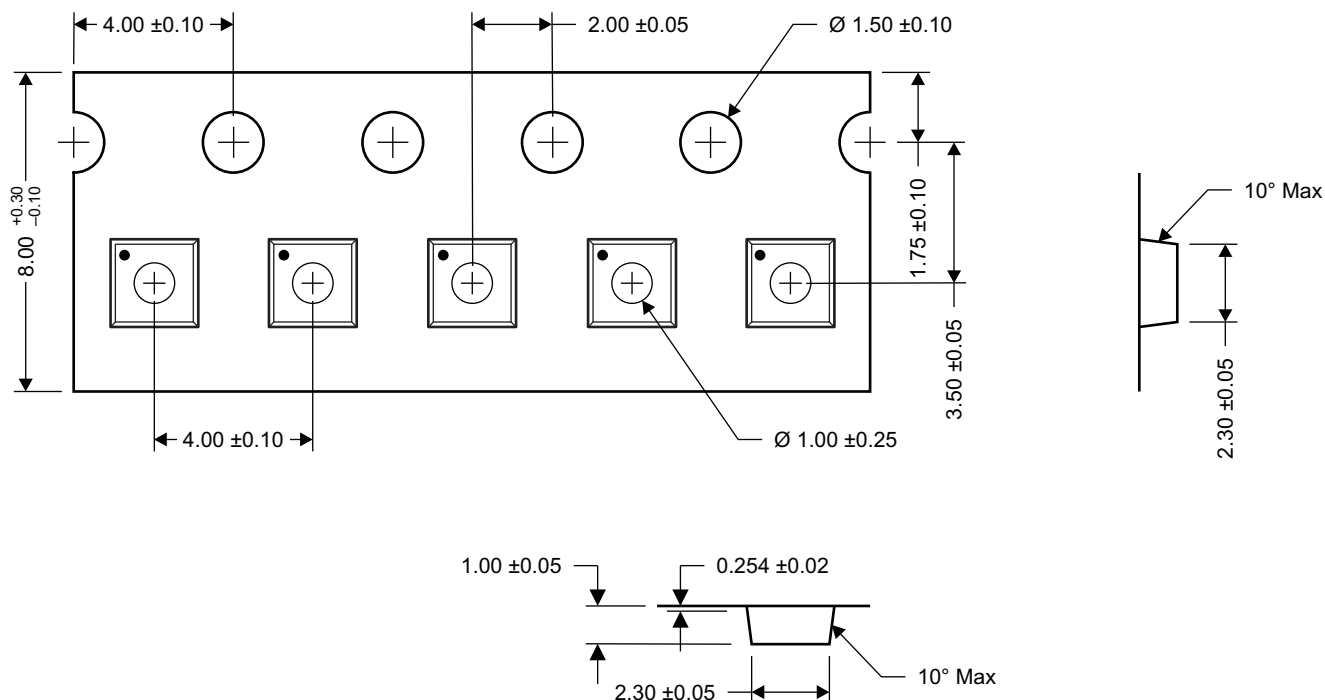
Recommended PCB Pattern



Note: All dimensions are in mm, unless otherwise specified.

For recommended circuit layout for PCB designs, see application note [SLPA005 – Reducing Ringing Through PCB Layout Techniques](#).

Q2 Tape and Reel Information



- Notes: 1. Measured from centerline of sprocket hole to centerline of pocket
- 2. Cumulative tolerance of 10 sprocket holes is ±0.20
- 3. Other material available
- 4. Typical SR of form tape Max 10<sup>9</sup> OHM/SQ
- 5. All dimensions are in mm, unless otherwise specified.

M0168-01

## REVISION HISTORY

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### Changes from Original (October 2009) to Revision A

Page

- Changed the Electrical Characteristics table -  $V_{GS(th)}$  MAX value From: 1.4V To 1.55V ..... 2
- 

### Changes from Revision A (December 2009) to Revision B

Page

- Added title to [Figure 11](#) - Single Pulse Unclamped Inductive Switching ..... 5
  - Deleted the Package Marking Information section ..... 8
-



**PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
CSD16301Q2	ACTIVE	SON	DQK	6	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	<a href="#">Request Free Samples</a>

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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Data Converters	<a href="http://dataconverter.ti.com">dataconverter.ti.com</a>	Automotive	<a href="http://www.ti.com/automotive">www.ti.com/automotive</a>
DLP® Products	<a href="http://www.dlp.com">www.dlp.com</a>	Communications and Telecom	<a href="http://www.ti.com/communications">www.ti.com/communications</a>
DSP	<a href="http://dsp.ti.com">dsp.ti.com</a>	Computers and Peripherals	<a href="http://www.ti.com/computers">www.ti.com/computers</a>
Clocks and Timers	<a href="http://www.ti.com/clocks">www.ti.com/clocks</a>	Consumer Electronics	<a href="http://www.ti.com/consumer-apps">www.ti.com/consumer-apps</a>
Interface	<a href="http://interface.ti.com">interface.ti.com</a>	Energy	<a href="http://www.ti.com/energy">www.ti.com/energy</a>
Logic	<a href="http://logic.ti.com">logic.ti.com</a>	Industrial	<a href="http://www.ti.com/industrial">www.ti.com/industrial</a>
Power Mgmt	<a href="http://power.ti.com">power.ti.com</a>	Medical	<a href="http://www.ti.com/medical">www.ti.com/medical</a>
Microcontrollers	<a href="http://microcontroller.ti.com">microcontroller.ti.com</a>	Security	<a href="http://www.ti.com/security">www.ti.com/security</a>
RFID	<a href="http://www.ti-rfid.com">www.ti-rfid.com</a>	Space, Avionics & Defense	<a href="http://www.ti.com/space-avionics-defense">www.ti.com/space-avionics-defense</a>
RF/IF and ZigBee® Solutions	<a href="http://www.ti.com/lprf">www.ti.com/lprf</a>	Video and Imaging	<a href="http://www.ti.com/video">www.ti.com/video</a>
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